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Characteristic		Symbol	Value	Units	
Drain-Source Voltage		V <sub>DSS</sub>	30	V	
Gate-Source Voltage			$V_{GSS}$	±20	V
Drain Current (Note 5)	Steady State	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	16 13	А
Pulsed Drain Current (Note 6)			I <sub>DM</sub>	64	Α

### **Thermal Characteristics**

Characteristic	Symbol	Value	Unit
Total Power Dissipation (Note 5)	$P_{D}$	2.5	W
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	50	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)		ı	<b>7</b> 1				
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	30	_	_	V	$V_{GS} = 0V, I_D = 250\mu A$	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	_	_	1	μА	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V	
Gate-Source Leakage	I <sub>GSS</sub>	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)		ā.					
Gate Threshold Voltage	$V_{GS(th)}$	1.1		2.0	V	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	
Static Drain-Source On-Resistance	R <sub>DS</sub> (ON)	_		9 13	mΩ	$V_{GS} = 10V, I_D = 16A$ $V_{GS} = 4.5V, I_D = 10A$	
Forward Transconductance	9fs	_	16	_	S	V <sub>DS</sub> = 10V, I <sub>D</sub> = 12A	
Diode Forward Voltage	V <sub>SD</sub>	0.5	_	1.2	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 16A	
DYNAMIC CHARACTERISTICS (Note 8)				•	•		
Input Capacitance	C <sub>iss</sub>	_	2096	_	pF	., , , , , , , , , , , , , , , , , , ,	
Output Capacitance	Coss	_	329	_	pF	V <sub>DS</sub> = 15V, V <sub>GS</sub> = 0V f = 1.0MHz	
Reverse Transfer Capacitance	C <sub>rss</sub>	_	258	_	pF	T = 1.0WH2	
Gate Resistance	$R_G$	_	1.2	_	Ω	V <sub>GS</sub> = 0V, f = 1MHz	
SWITCHING CHARACTERISTICS (Note 8)							
Total Gate Charge	$Q_g$	_	22.4 43.7	_	nC	$V_{DS}$ = 15V, $V_{GS}$ = 4.5V, $I_{D}$ = 16A $V_{DS}$ = 15V, $V_{GS}$ = 10.0V, $I_{D}$ = 16A	
Gate-Source Charge	Q <sub>gs</sub>	_	5.5	_		$V_{DS} = 15V$ , $V_{GS} = 10V$ , $I_D = 16A$	
Gate-Drain Charge	$Q_{gd}$	_	12.6	_		$V_{DS}$ = 15V, $V_{GS}$ = 10V, $I_{D}$ = 16A	
Turn-On Delay Time	t <sub>d(on)</sub>	_	7.11	_	20		
Rise Time	t <sub>r</sub>	_	10.3	_		V <sub>GS</sub> = 10V, V <sub>DS</sub> = 15V,	
Turn-Off Delay Time	t <sub>d(off)</sub>		58.3		ns	$R_D = 15\Omega$ , $R_G = 6\Omega$	
Fall Time	t <sub>f</sub>		32.1	_			

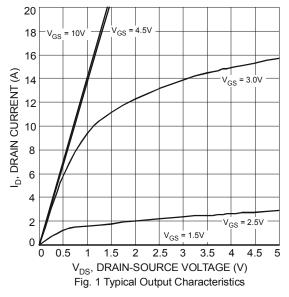
Notes: 5 Device mounted on 2 oz. Copper pads on FR-4 PCB, with  $R_{\theta JA}$  = +50°C

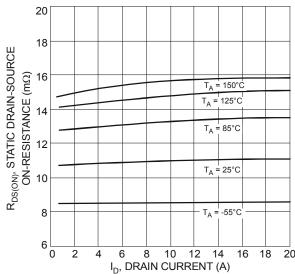
6. Pulse width  $\leq 10 \mu S$ , Duty Cycle  $\leq 1\%$ .

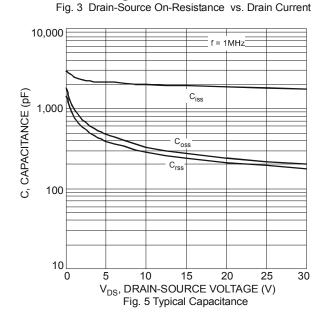
<sup>7.</sup> Short duration pulse test used to minimize self-heating effect.

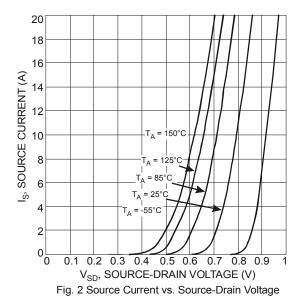
<sup>8.</sup> Guaranteed by design. Not subject to product testing.

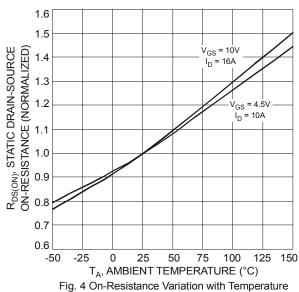


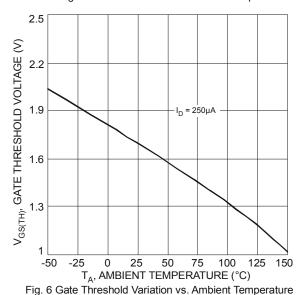




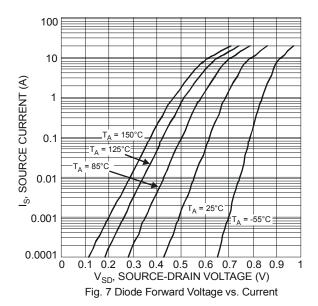










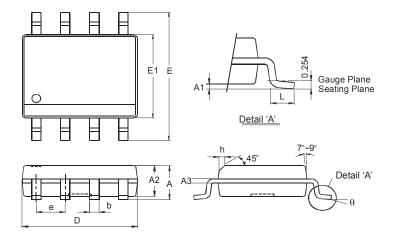


0.1 D = 0.1 D = 0.05 D = 0.005 D = 0

t<sub>1</sub>, PULSE DURATION TIME (s) Fig. 8 Transient Thermal Response

## **Package Outline Dimensions**

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version

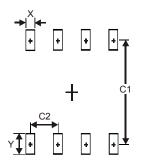


SO-8				
Dim	Min	Max		
Α	1	1.75		
<b>A</b> 1	0.10	0.20		
A2	1.30	1.50		
А3	0.15	0.25		
b	0.3	0.5		
D	4.85	4.95		
E	5.90	6.10		
E1	3.85	3.95		
е	1.27 Typ			
h	ı	0.35		
L	0.62	0.82		
θ	0°	8°		
All Dimensions in mm				



### Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X	0.60
Y	1.55
C1	5.4
C2	1.27

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